

**Features**

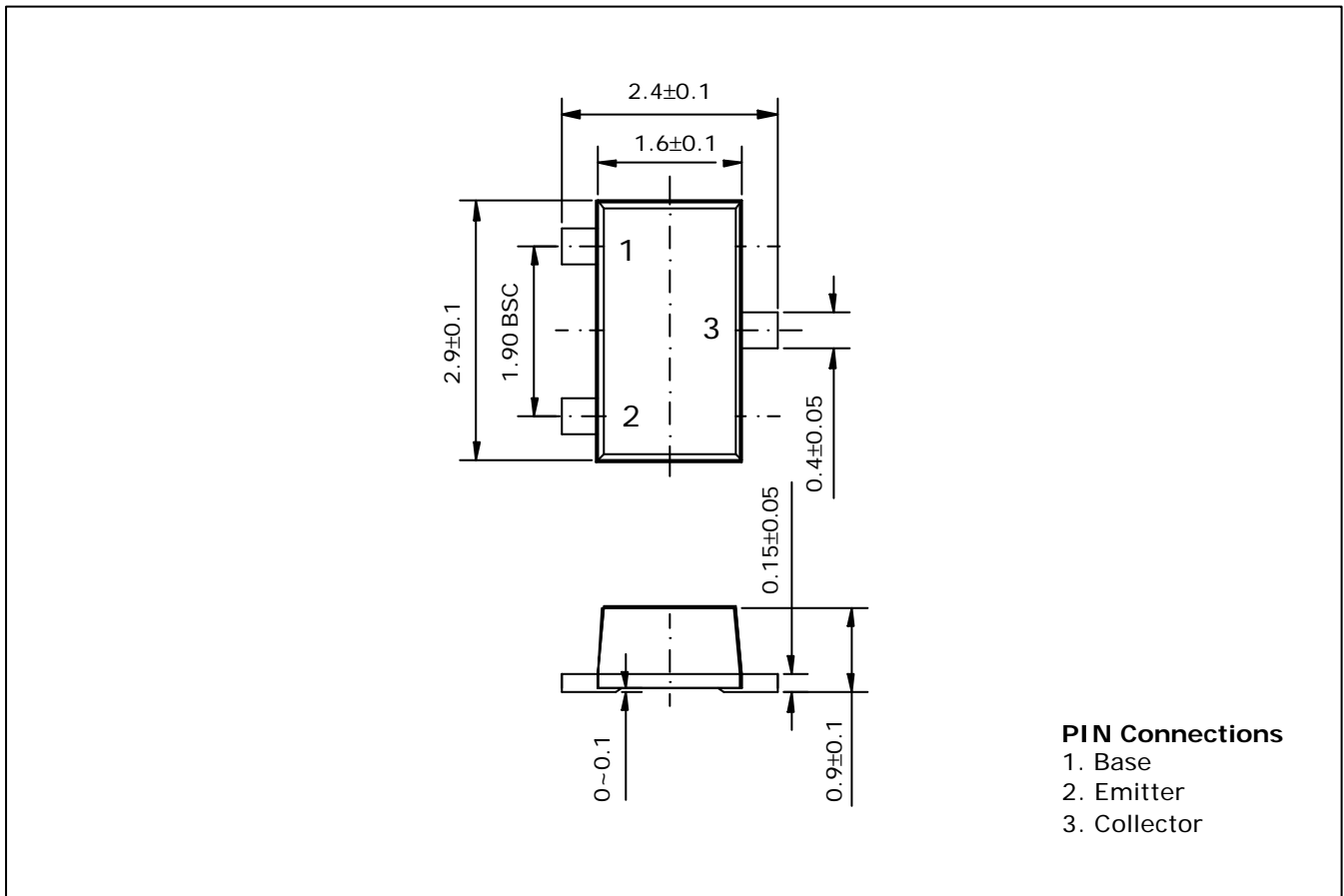
- Extremely low collector-to-emitter saturation voltage  
(  $V_{CE(SAT)} = -0.08V$  Typ. @  $I_C/I_B = -100mA/-10mA$  )
- Suitable for low voltage large current drivers
- Complementary pair with DN050S
- Switching Application

**Ordering Information**

Type NO.	Marking	Package Code
DP050S	P02	SOT-23F

**Outline Dimensions**

**unit : mm**



## Absolute maximum ratings

(Ta=25° C)

Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	$V_{CBO}$	-15	V
Collector-Emitter voltage	$V_{CEO}$	-12	V
Emitter-Base voltage	$V_{EBO}$	-5	V
Collector current	$I_C$	-500	mA
Collector dissipation	$P_C$	200	mW
Junction temperature	$T_J$	150	°C
Storage temperature	$T_{stg}$	-55 ~ 150	°C

## Electrical Characteristics

(Ta=25° C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base breakdown voltage	$BV_{CBO}$	$I_C = -50\mu A, I_E = 0$	-15	-	-	V
Collector-Emitter breakdown voltage	$BV_{CEO}$	$I_C = -1mA, I_B = 0$	-12	-	-	V
Emitter-Base breakdown voltage	$BV_{EBO}$	$I_E = -50\mu A, I_C = 0$	-5	-	-	V
Collector cut-off current	$I_{CBO}$	$V_{CB} = -12V, I_E = 0$	-	-	-0.1	$\mu A$
Emitter cut-off current	$I_{EBO}$	$V_{EB} = -5V, I_C = 0$	-	-	-0.1	$\mu A$
DC current gain	$h_{FE1}$	$V_{CE} = -1V, I_C = -100mA$	200	-	450	-
	$h_{FE2}$	$V_{CE} = -1V, I_C = -500mA$	70	-	-	-
Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_C = -100mA, I_B = -10mA$	-	-	-0.25	V
Base-Emitter saturation voltage	$V_{BE(sat)}$	$I_C = -100mA, I_B = -10mA$	-	-	-1.2	V
Transition frequency	$f_T$	$V_{CE} = -5V, I_C = -20mA$	-	100	-	MHz
Collector output capacitance	$C_{ob}$	$V_{CB} = -10V, I_E = 0, f = 1MHz$	-	8.0	-	pF

Electrical Characteristic Curves

Fig. 1  $P_C - T_a$

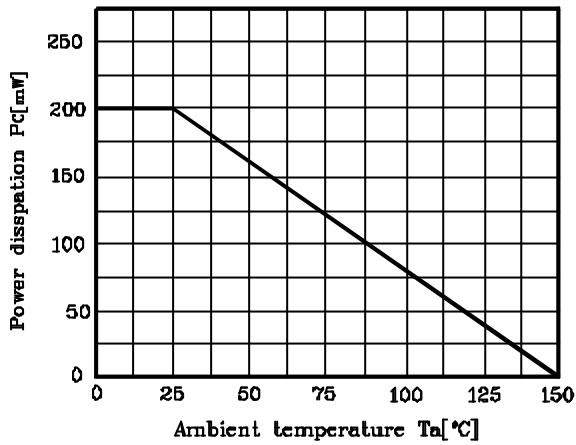


Fig. 2  $I_C - V_{BE}$

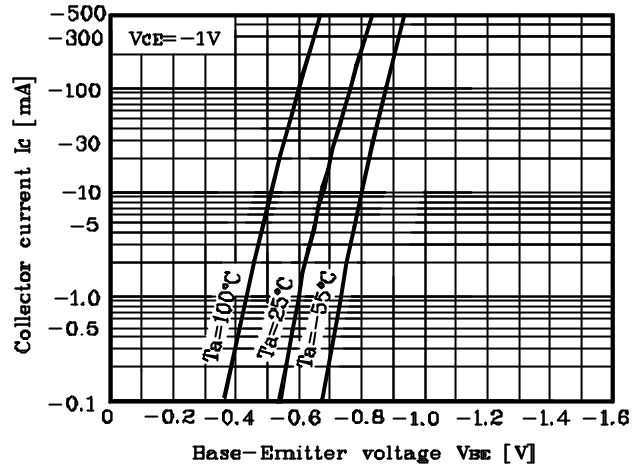


Fig. 3  $h_{FE} - I_C$

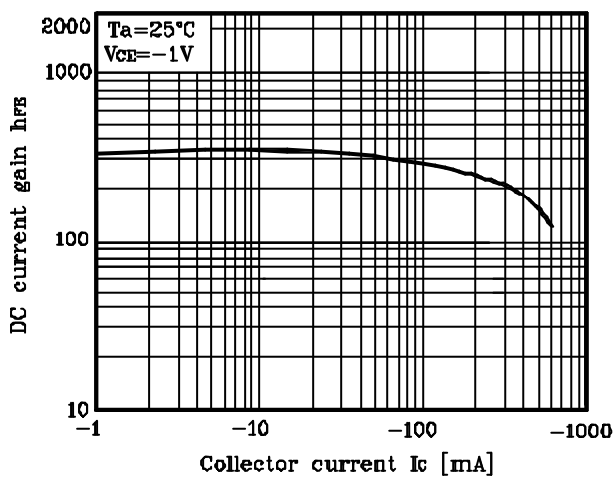


Fig. 4  $I_C - V_{CE}$

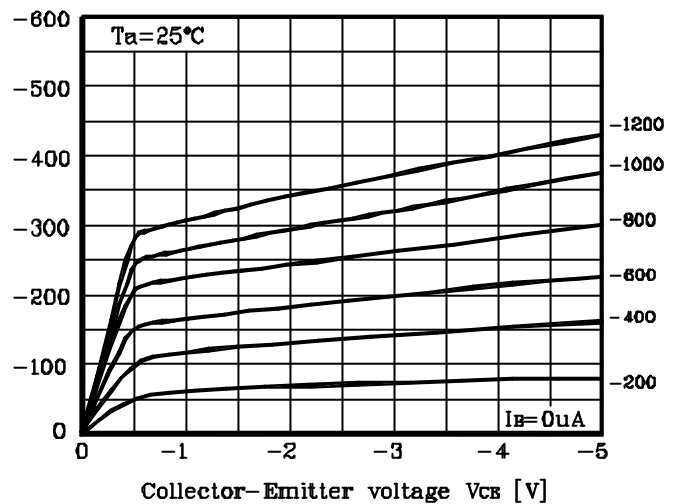


Fig. 5  $V_{CE(sat)} - I_C$

